## DATA SHEET



## BA316; BA317; BA318 High-speed diodes

## FEATURES

- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- General application
- Continuous reverse voltage: 10 V , $30 \mathrm{~V}, 50 \mathrm{~V}$
- Repetitive peak reverse voltage: max. $15 \mathrm{~V}, 40 \mathrm{~V}, 60 \mathrm{~V}$
- Repetitive peak forward current: max. 225 mA .


## DESCRIPTION

The BA316, BA317, BA318 are high-speed switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD27 (DO-35) packages.

## APPLICATIONS

- High-speed switching.
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The diodes are type branded.
Fig. 1 Simplified outline (SOD27; DO-35) and symbol.

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {RRM }}$ | repetitive peak reverse voltage <br> BA316 <br> BA317 <br> BA318 |  | $\begin{aligned} & \text { - } \\ & \text { - } \\ & \text { - } \end{aligned}$ | $\begin{aligned} & 15 \\ & 40 \\ & 60 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{R}}$ | continuous reverse voltage <br> BA316 <br> BA317 <br> BA318 |  |  | $\begin{aligned} & 10 \\ & 30 \\ & 50 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{F}}$ | continuous forward current | see Fig.2; note 1 | - | 100 | mA |
| $\mathrm{I}_{\text {FRM }}$ | repetitive peak forward current |  | - | 225 | mA |
| $\mathrm{I}_{\text {FSM }}$ | non-repetitive peak forward current | square wave; $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ prior to surge; see Fig. 4 $\begin{aligned} & t=1 \mu \mathrm{~s} \\ & \mathrm{t}=1 \mathrm{~ms} \\ & \mathrm{t}=1 \mathrm{~s} \end{aligned}$ |  | $\begin{aligned} & 4 \\ & 1 \\ & 0.5 \end{aligned}$ | $\begin{aligned} & \mathrm{A} \\ & \mathrm{~A} \\ & \mathrm{~A} \end{aligned}$ |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$; note 1 | - | 350 | mW |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  | -65 | +200 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | junction temperature |  | - | 200 | ${ }^{\circ} \mathrm{C}$ |

## Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm .

## ELECTRICAL CHARACTERISTICS

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{F}$ | forward voltage | $\begin{array}{\|c} \hline \text { see Fig. } 3 \\ \mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA} \\ \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA} \\ \mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA} \\ \hline \end{array}$ | _ | $\begin{array}{r} 700 \\ 850 \\ 1100 \end{array}$ | $\begin{aligned} & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \end{aligned}$ |
| $\mathrm{I}_{\mathrm{R}}$ | reverse current <br> BA316 <br> BA317 <br> BA318 | $\begin{aligned} & \hline \text { see Fig. } 5 \\ & \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{R}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=30 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=30 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{R}}=30 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=50 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{R}}=50 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | $\begin{aligned} & \text { - } \\ & \text { - } \\ & \text { - } \\ & \text { - } \end{aligned}$ | $\begin{array}{r} 200 \\ 100 \\ 50 \\ 200 \\ 100 \\ 50 \\ 200 \\ 100 \end{array}$ | nA <br> $\mu \mathrm{A}$ <br> nA <br> nA <br> $\mu \mathrm{A}$ <br> nA <br> nA <br> $\mu \mathrm{A}$ |
| $\mathrm{C}_{\mathrm{d}}$ | diode capacitance | $\mathrm{f}=1 \mathrm{MHz} ; \mathrm{V}_{\mathrm{R}}=0$; see Fig. 6 | - | 2 | pF |
| $\mathrm{t}_{\mathrm{rr}}$ | reverse recovery time | when switched from $I_{F}=10 \mathrm{~mA}$ to $\mathrm{I}_{\mathrm{R}}=60 \mathrm{~mA} ; \mathrm{R}_{\mathrm{L}}=100 \Omega$; <br> measured at $\mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}$; see Fig. 7 | - | 4 | ns |
| $\mathrm{V}_{\mathrm{fr}}$ | forward recovery voltage | when switched from $\mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}$; $\mathrm{t}_{\mathrm{r}}=20 \mathrm{~ns}$; see Fig. 8 | - | 2.5 | V |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
| :--- | :--- | :--- | :---: | :---: |
| $R_{\text {th j-tp }}$ | thermal resistance from junction to tie-point | lead length 10 mm | 240 | K/W |
| $R_{\text {th } j \text { j-a }}$ | thermal resistance from junction to ambient | lead length 10 mm ; note 1 | 500 | K/W |

## Note

1. Device mounted on a printed circuit-board without metallization pad.

## GRAPHICAL DATA



Device mounted on an FR4 printed-circuit board; lead length 10 mm .
Fig. 2 Maximum permissible continuous forward current as a function of ambient temperature.

(1) $\mathrm{T}_{\mathrm{j}}=175^{\circ} \mathrm{C}$; typical values.
(2) $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$; typical values.
(3) $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$; maximum values.

Fig. 3 Forward current as a function of forward voltage.


Fig. 4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.



Fig. 7 Reverse recovery voltage test circuit and waveforms.


## PACKAGE OUTLINE

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## DEFINITIONS

| Data Sheet Status |  |
| :--- | :--- |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or <br> more of the limititg values may cause permanent damage to the device. These are stress ratings only and operation <br> of the device at these or at any other conditions above those given in the Characteristics sections of the specification <br> is not implied. Exposure to limiting values for extended periods may affect device reliability. |
| Application information |  |
| Where application information is given, it is advisory and does not form part of the specification. |  |

## LIFE SUPPORT APPLICATIONS

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